

# RJH60A83RDPE

600V - 10A - IGBT Application: Inverter R07DS0806EJ0200 Rev.2.00 Jul 12, 2012

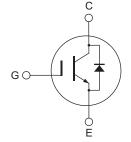
### **Features**

- Reverse conducting IGBT with monolithic diode
- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage  $V_{CE(sat)} = 2.1 \text{ V typ.}$  (at  $I_C = 10 \text{ A}$ ,  $V_{GE} = 15 \text{ V}$ ,  $Ta = 25^{\circ}\text{C}$ )
- Built-in fast recovery diode ( $t_{rr} = 130 \text{ ns typ.}$ ) in one package
- Trench gate and thin wafer technology
- High speed switching  $t_f$  = 45 ns typ. (at  $V_{CC}$  = 300 V,  $V_{GE}$  = 15 V,  $I_C$  = 10 A, Rg = 5  $\Omega$ , Ta = 25°C, inductive load)

#### **Outline**

RENESAS Package code: PRSS0004AE-B (Package name: LDPAK (S)-(1) )





- 1. Gate
- 2. Collector
- 3. Emitter
- 4. Collector

### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	600	V
Gate to emitter voltage		V <sub>GES</sub>	±30	V
Collector current	Tc = 25°C	I <sub>C</sub>	20	Α
	Tc = 100°C	I <sub>C</sub>	10	Α
Collector peak current		Ic(peak) Note1	40	Α
Collector to emitter diode forward current		i <sub>DF</sub>	10	Α
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) Note1	40	Α
Collector dissipation		P <sub>C</sub> Note2	52	W
Junction to case thermal resistance		θj-c Note2	2.38	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tc = 25°C

### **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

ltem	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage	V <sub>(BR)CES</sub>	600	_	_	<b>V</b>	$I_C = 10 \mu A, V_{GE} = 0$	
Zero gate voltage collector current / diode reverse current	I <sub>CES</sub> / I <sub>R</sub>	_	_	1	μА	V <sub>CE</sub> = 600 V, V <sub>GE</sub> = 0 V	
Gate to emitter leak current	I <sub>GES</sub>	_	_	±100	nA	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0 \text{ V}$	
Gate to emitter cutoff voltage	$V_{\text{GE(off)}}$	4.5	_	7.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	$V_{CE(sat)}$	_	2.1	2.6	V	$I_C = 10 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V <sub>CE(sat)</sub>	_	3.1		V	$I_C = 20 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	280		pF	V <sub>CE</sub> = 25 V	
Output capacitance	Coes	_	19	_	pF	$V_{GE} = 0 V$	
Reveres transfer capacitance	Cres	_	11	_	pF	f = 1 MHz	
Total gate charge	Qg	_	19.7	_	nC	V <sub>GE</sub> = 15 V V <sub>CE</sub> = 300 V I <sub>C</sub> = 10 A	
Gate to emitter charge	Qge	_	3.4	_	nC		
Gate to collector charge	Qgc	_	12.0	_	nC		
Turn-on delay time	t <sub>d(on)</sub>	_	31	_	ns	$V_{CC} = 300V$ $V_{GE} = 15 V$ $I_{C} = 10 A,$ $Rg = 5 \Omega$ Inductive load	
Rise time	t <sub>r</sub>	_	14	_	ns		
Turn-off delay time	$t_{d(off)}$	_	54	_	ns		
Fall time	t <sub>f</sub>	_	45		ns		
Turn-on energy	Eon	_	0.23	_	mJ		
Turn-off energy	E <sub>off</sub>	_	0.16	_	mJ		
Total switching energy	E <sub>total</sub>	_	0.39	_	mJ	1	
Short circuit withstand time	t <sub>sc</sub>	3.0	5.0	_	μS	$V_{CE} \le 360 \text{ V}, V_{GE} = 15 \text{ V}$ Tj=100°C	
FRD Forward voltage	V <sub>F</sub>	I _	2.3	Γ_	V	I <sub>F</sub> = 10 A <sup>Note3</sup>	
FRD reverse recovery time	t <sub>rr</sub>		130		ns	I <sub>F</sub> = 10 A	
<b>,</b>	1	ļ		1	-	վ ՝	

0.28

5.9

 $Q_{rr}$ 

Irr

Notes: 3. Pulse test.

FRD reverse recovery charge

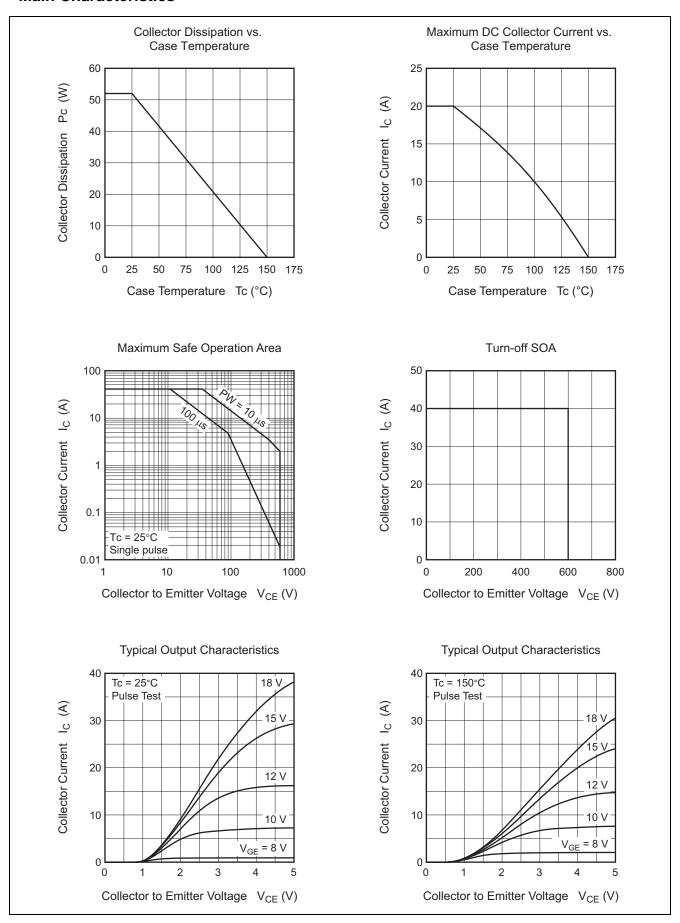
FRD peak reverse recovery current

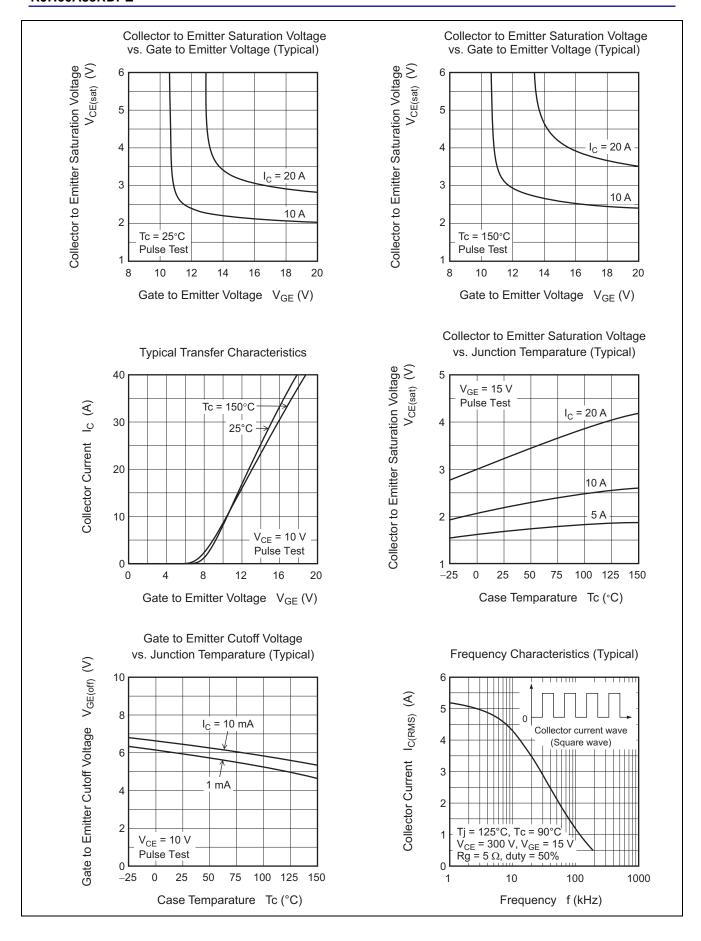
 $di_F/dt = 100 A/\mu s$ 

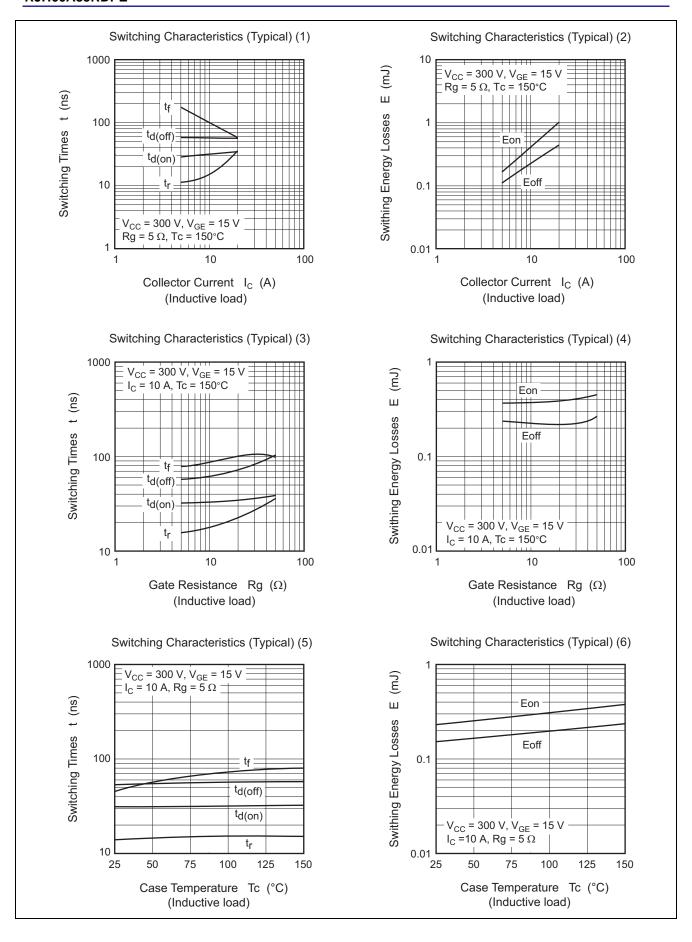
μС

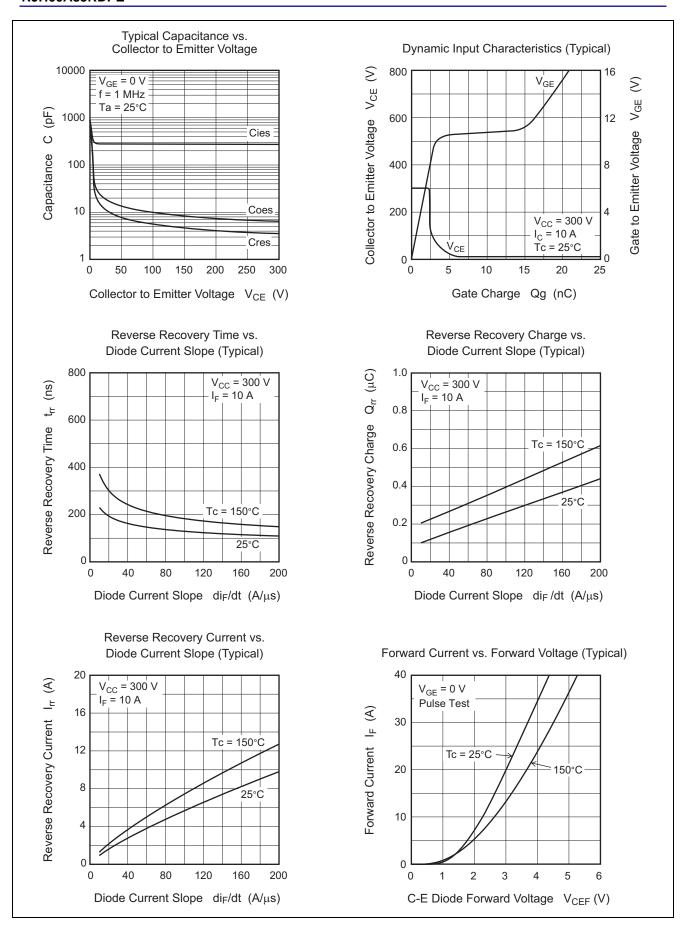
Α

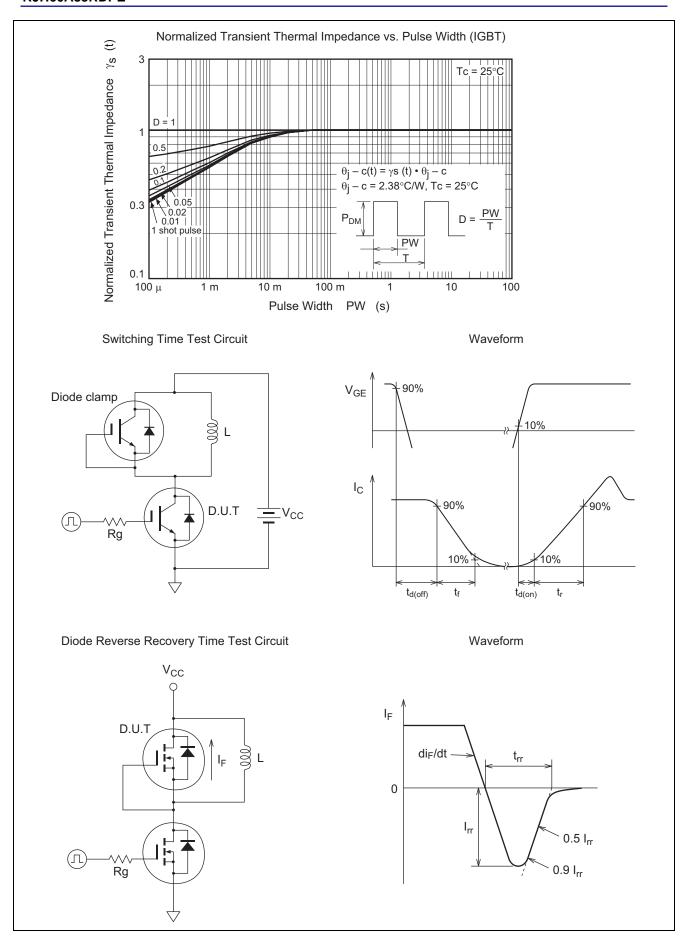
### **Main Characteristics**



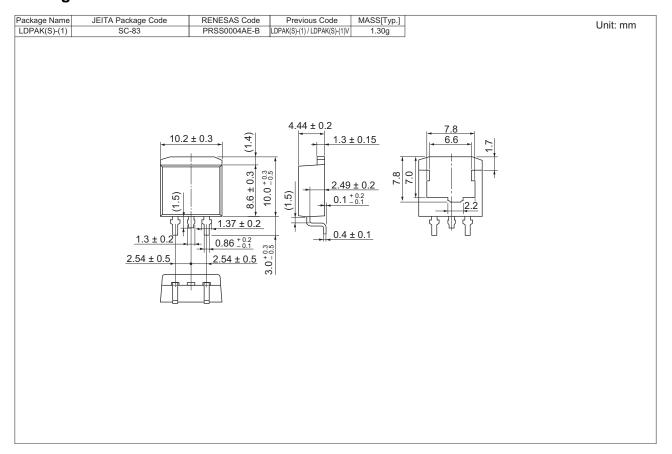








## **Package Dimension**



## **Ordering Information**

Orderable Part No.	Quantity	Shipping Container
RJH60A83RDPE-00#J3	1000 pcs	Taping

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